Solid State Lasers: Materials and Applications

Sino-American Topical Meeting and Tabletop Exhibit

Technical Digest

July 8–11, 1997 Nankai University Tlanjin, PRC





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OSA—Optical Society of America
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Crystal growth, structural and full optical characterizations of 3-Methyl-4-methoxy-4'-nitrostilben (MMONS)

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Organic crystals with large second-order nonlinear optical (NLO) susceptibilities are of great interest because of their potential use of optical parametric generation. (1) In recent years second-order cascading effects in organic crystals draw much attention not only in the context of basic understandings of the nonlinear optical processes but also potential applications in optoelectronics.

3-Methyl-4-methoxy-4'-nitrostilben (MMONS) is a very promising organic NLO material and the preliminary studies on nonlinear optical properties were reported by Bierlein et al. (2) Single crystals of a large size (40×30×30mm³) and of high perfection was successfully grown by solution growth method using methyl ethyl ketone as a solvent. A good quality seed was introduced into the saturated solution and the temperature of the solution was lowered to establish supersaturation at the rate of 0.3°C/day. The crystal structure of MMONS was determined by single crystal X-ray diffraction using a Enraf-Nonius CAD-4 diffractometer. MMONS crystals belong to space group Aba2 (point group mm2, Z=8) with lattice parameters a = 15.750 Å, b = 13.470 Å, c = 13.356 Å. (3) Fig. 1 shows the molecular structure of MMONS. The MMONS molecule has a permanent dipole moment along the charge transfer axis. When it is crystallized, the molecular dipole moments are summed up to cancel out each other in the crystallographic a- and b-axes, but a net dipole mement remains along the polar caxis, which manifests strong polar nature of the crystal. This polar nature not only strongly affects the crystal growth process but also overall linear and nonlinear optical properties. Defects in a crystal can affect not only mechanical properties but also optical properties as well. It was therefore necessary to make a defect characterization by using white beam synchrotron Xray topography. The X-ray topographs of 002 reflection reveal the details of growth sector boundary, strain fields and dislocations of mixed type. The dislocation density was estimated to be an order of 10²/cm². Laser damage threshold was measured on the (100) plane by using the pulsed Nd:YAG laser. The damage threshold was 56 MW/cm2 for 8 ns pulses, while the threshold goes up as high as 17 GW/cm² for the beam of 30 ps pulse width. From the linear

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refractive index data of MMONS, the phase matching angles for type I and type II and the corresponding walk-off angles were calculated. The type II phase matching at $(\theta, \phi) = (73.13^{\circ}, 0^{\circ})$ gives the largest value of the effective second-order nonlinear coefficient, $d_{eff} = 59 \text{ pm/V}$. The full coefficients of the second-order nonlinear susceptibility tensor were measured by using the Maker fringe technique [Fig.2] and d_{31} component was determined for the first time. However the measured value of d_{33} (80 pm/V) is smaller than that of Bierlein's and this is probably due to the fact that Bierlein et al used the wrong d_{33} value of KTP as a reference. Utilizing the birefringence of the crystal, the second harmonic generations of type I and type II collinear phase matchings were exploited. Maximum conversion efficiencies of 2.5 % for type I and 13 % for type II were obtained at 1064 nm.

Nonlinear refractive indices and absorption coefficients were measured by using Z-scan technique at 532 nm and 1064 nm for the polarizations parallel to the crystallographic b- and c-axes[Fig.3]. Linear absorption coefficients were also derived from the Z-scan geometry. The measured values of nonlinear refractive index n_2 , two-photon absorption coefficient β and linear absorption coefficient α_0 are summarized in Table 1, where $n = n_0 + n_2 |E|^2/2$ and $\alpha = \alpha_0 + \beta I$. The linear absorption coefficients for the polar c-direction are twice as large as those for the nonpolar b-direction both at the fundamental and harmonic wavelengths, which is the consequence of highly anisotropic distribution of π -electrons along the polar c-axis. The much larger values of the nonlinear refractive index n_2 and the two-photon absorption coefficient β in the polar c-direction than those in the nonpolar b-direction clearly indicate that the nonlinear effect occurs predominantly along the molecular charge transfer direction. Open aperture Z-scan data shows that the multiphoton rather than two-photon processes are involved at 1064 nm. Assuming that three-photon absorption dominate in the nonlinear absorption processes at 1064 nm, the three-photon absorption coefficient for the c-polarization was estimated to be $\eta = -0.62 \text{ cm}^3/\text{GW}^2$.

Table 1	Complex	nonlinear	refractive	indices	and linear	· abcorntion	coefficients.
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	λ =	532 nm	$\lambda = 1064 \text{ nm}$		
	b-polarization	c-polarization	b-polarization	c-polarization	
$\alpha_0 (\text{cm}^{-1})$	2.24	4.95	0.54	1.01	
β(cm/GW)	7.37	34.2	0	0	
$n_2(10^{-12} \text{ esu})$	4.9	71.8	1.9	5.6	

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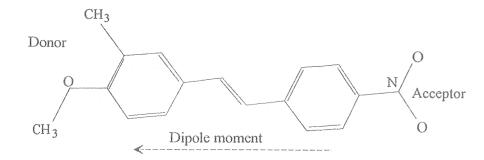


Fig.1 Molecular structure of MMONS.

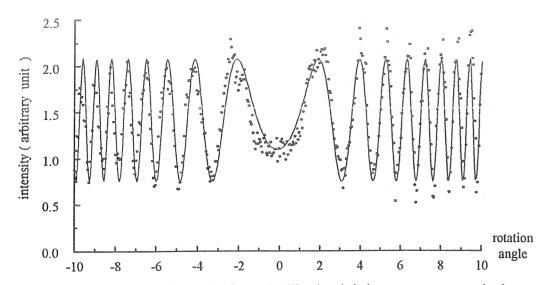


Fig.2 Maker fringe of a-cut MMONS sample. The closed circles represent measured values and the solid curve calculated one.

